

Symbol	Parameter	Ratings	Units		
V _{DSS}	Drain-to-Source Voltage		40	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	240	Α	
	Pulsed Drain Current	T _C = 25°C	See Figure 4		
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	316	mJ	
P _D	Power Dissipation		300	W	
	Derate Above 25°C		2.0	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.5	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

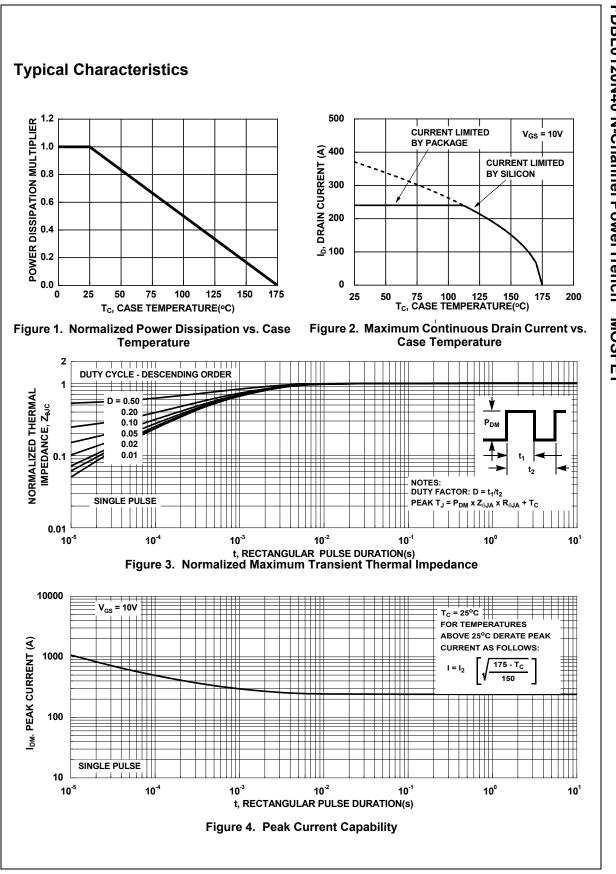
Notes:

Current is limited by bondwire configuration.
Starting T_J = 25°C, L = 0.1mH, I_{AS} = 79.5A, V_{DD} = 40V during inductor charging and V_{DD} = 0V during time in avalanche.
R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

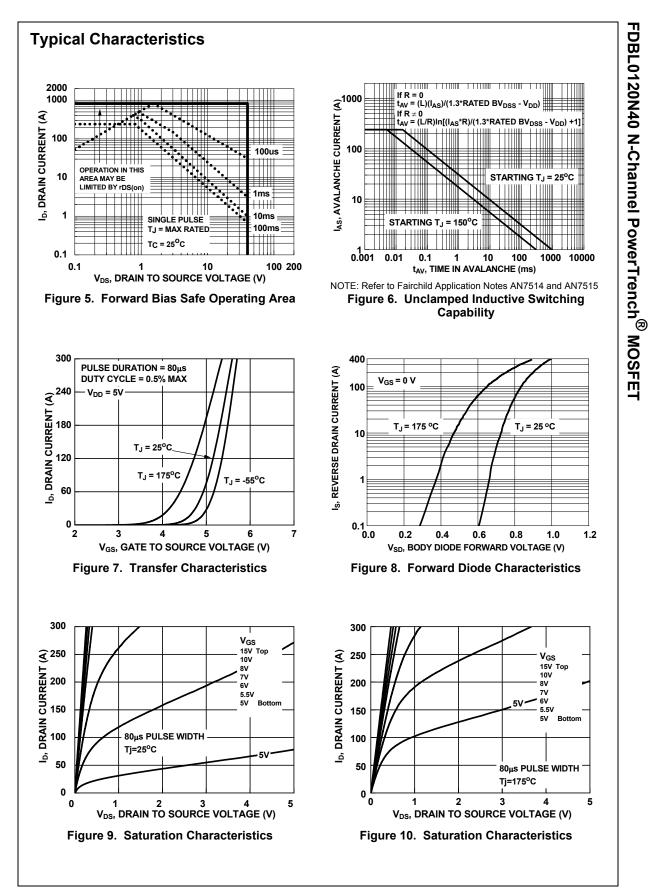
Package Marking and Ordering Information

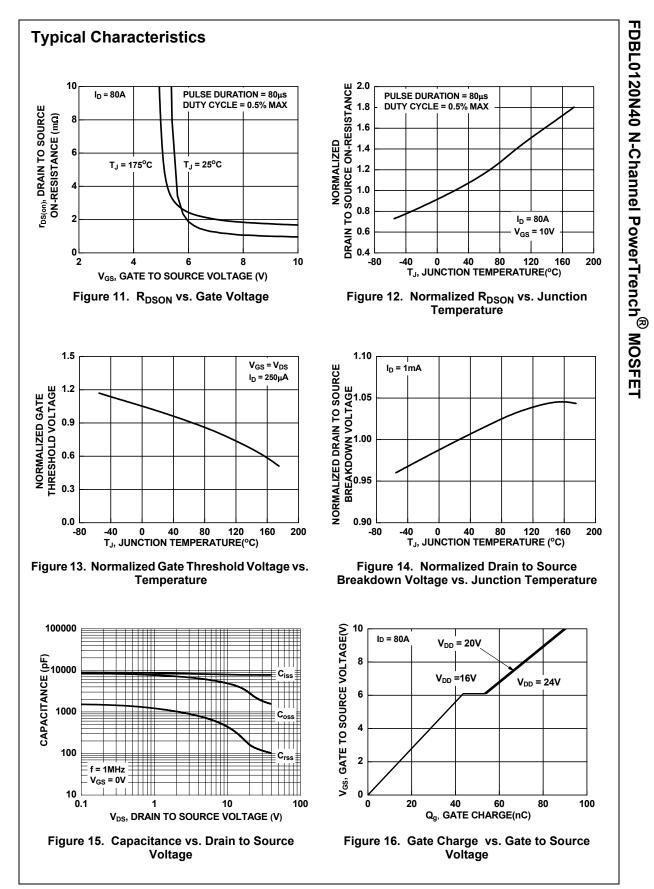
Device Marking	Device	Package			
FDBL0120N40	FDBL0120N40	MO-299A	-	-	-

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units	
-	racteristics							
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, \	/ _{cs} = (V	40	-	-	V
1000	Drain-to-Source Leakage Current	V _{DS} =40V,			-	-	1	μA
I _{DSS}		20	·	75 ^o C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA	
On Cha	racteristics					-1		1
V _{GS(th)}	Gate to Source Threshold Voltage	Vec = Vec l	- = 25(DuA	2.0	3.2	4.0	V
- ບວ(ເກ)	.	$\label{eq:VGS} \begin{array}{ c c c } V_{GS} = V_{DS}, \ I_D = 250 \mu A \\ \hline I_D = 80A, & T_J = 25^{\circ}C \\ V_{GS} = 10V & T_J = 175^{\circ}C \ (Note \ 4) \end{array}$		-	0.90	1.20	mΩ	
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	$T_1 = 1$	75 ^o C (Note 4)	-	1.64	1.86	mΩ
C _{iss}	Input Capacitance	$-V_{DS} = 25V. V_{CS} = 0V.$		-	7735	-	pF	
	Input Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz f = 1MHz		-		-	pF	
C _{oss}	Output Capacitance			-	2160	-	pF	
C _{rss}	Reverse Transfer Capacitance			-	129	-	pF	
R _g	Gate Resistance			-	2.5	-	Ω	
Q _{g(ToT)}	Total Gate Charge at 10V	$V_{GS} = 0$ to 10		V _{DD} = 32V	-	90	107	nC
Q _{g(th)}	Threshold Gate Charge	$V_{GS} = 0$ to 2V	$V_{GS} = 0$ to 2V $I_D = 80A$		-	13.5	15.5	nC
Q _{gs}	Gate-to-Source Gate Charge				-	43	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge				-	10	-	nC
Switchi	ng Characteristics							
t _{on}	Turn-On Time	V _{DD} = 20V, I _D = 80A, V _{GS} = 10V, R _{GEN} = 6Ω			-	-	102	ns
t _{d(on)}	Turn-On Delay			F	-	33	-	ns
t _r	Rise Time			А,	-	40	-	ns
d(off)	Turn-Off Delay			= 6Ω	-	47	-	ns
t _f	Fall Time				-	23	-	ns
t _{off}	Turn-Off Time			-	-	91	ns	
Drain-S	ource Diode Characteristics							
V _{SD}	Source-to-Drain Diode Voltage	tage $\frac{I_{SD} = 80A, V_{GS} = 0V}{I_{SD} = 40A, V_{GS} = 0V}$			-	-	1.25	V
• 50	Boarde to Brain Blode Voltage			V	-	-	1.2	V
t _{rr}	Reverse-Recovery Time	I _F = 80A, dI _s	_{SD} /dt =	100A/μs,	-	91	107	ns
Q _{rr}	Reverse-Recovery Charge	V _{DD} =32V		-	128	167	nC	



FDBL0120N40 N-Channel PowerTrench[®] MOSFET





FDBL0120N40 Rev.C3



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